


**APPLICATION DATA SHEET**

Electronic Version v14

Stylesheet Version v14.0

<b>Title of Invention</b>	METHOD OF FABRICATING POLY-CRYSTAL ITO FILM AND POLYCRYSTAL ITO ELECTRODE		
<b>Application Type :</b>		regular, utility	
<b>Attorney Docket Number :</b>		14150-US-PA	
<b>Correspondence address:</b>			
<b>Customer Number:</b>		31561	
<b>Priority Data:</b>			
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